

# RHRG75120

Data Sheet

### November 2013

# 75 A, 1200 V, Hyperfast Diode

The RHRG75120 is a hyperfast diode with soft recovery characteristics. It has the half recovery time of ultrafast diodes and is silicon nitride passivated ionimplanted epitaxial planar construction. These devices are intended to be used as freewheeling/ clamping diodes and diodes in a variety of switching power supplies and other power switching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

### Features

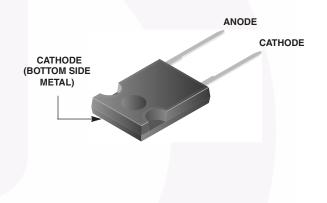
- Hyperfast Recovery t<sub>rr</sub> = 100 ns (@ I<sub>F</sub> = 75 A)
- Max Forward Voltage,  $V_F$  = 3.2 V (@  $T_C$  = 25°C)
- 1200 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- RoHS Compliant

### Applications

- Switching Power Supplies
- Power Switching Circuits
- General Purpose

### Packaging

### JEDEC STYLE TO-247



### **Ordering Information**

PART NUMBER	PACKAGE	BRAND
RHRG75120	TO-247-2L	RHRG75120

NOTE: When ordering, use the entire part number.

### Symbol



### **Absolute Maximum Ratings** $T_C = 25^{\circ}C$

	RHRG75120	UNIT
Peak Repetitive Reverse Voltage	1200	V
Working Peak Reverse Voltage	1200	V
DC Blocking Voltage	1200	V
Average Rectified Forward CurrentIF(AV)	75	А
$(T_{C} = 42^{\circ}C)$		
Repetitive Peak Surge Current I <sub>FRM</sub>	150	А
(Square Wave, 20 kHz)		
Nonrepetitive Peak Surge Current I <sub>FSM</sub>	500	А
(Halfwave, 1 Phase, 60 Hz)		
Maximum Power Dissipation	190	W
Avalanche Energy (See Figures 7 and 8) E <sub>AVL</sub>	50	mJ
Operating and Storage Temperature	-65 to 175	°C

SYMBOL	TEST CONDITION	MIN	ТҮР	МАХ	UNIT
V <sub>F</sub>	I <sub>F</sub> = 75 A	-	-	3.2	V
	I <sub>F</sub> = 75 A, T <sub>C</sub> = 150 <sup>o</sup> C	-	-	2.6	V
I <sub>R</sub>	V <sub>R</sub> = 1200 V	-	-	250	μΑ
	$V_{R} = 1200 V, T_{C} = 150^{\circ}C$	-	-	2	mA
T <sub>rr</sub>	$I_{F} = 1 \text{ A}, \ dI_{F}/dt = 100 \text{ A}/\mu \text{s}$	-	-	85	ns
	$I_F = 75 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}$	-	-	100	ns
t <sub>a</sub>	$I_F = 75 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}$	-	60	-	ns
t <sub>b</sub>	I <sub>F</sub> = 75 A, dI <sub>F</sub> /dt = 100 A/μs	-	25	-	ns
R <sub>θJC</sub>		-	-	0.8	°C/W

### **Electrical Specifications** $T_C = 25^{\circ}C$ , Unless Otherwise Specified

DEFINITIONS

 $V_F$  = Instantaneous forward voltage (pw = 300 µs, D = 2%).

I<sub>B</sub> = Instantaneous reverse current.

 $T_{rr}$  = Reverse recovery time (See Figure 6), summation of  $t_a + t_b$ .

 $t_a$  = Time to reach peak reverse current (See Figure 6).

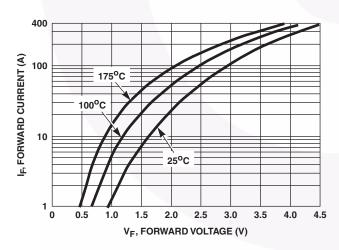
 $t_b$  = Time from peak  $I_{RM}$  to projected zero crossing of  $I_{RM}$  based on a straight line from peak  $I_{RM}$  through 25% of  $I_{RM}$  (See Figure 6).

 $R_{\theta JC}$  = Thermal resistance junction to case.

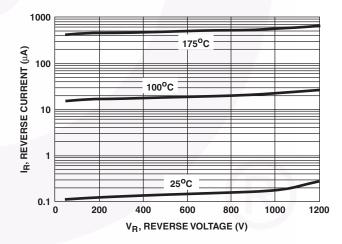
pw = Pulse width.

D = Duty cycle.

### **Typical Performance Curves**









## Typical Performance Curves (Continued)

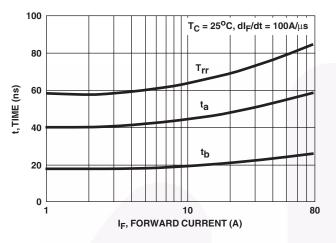
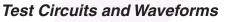


FIGURE 3. T<sub>rr</sub>, t<sub>a</sub> AND t<sub>b</sub> CURVES vs FORWARD CURRENT



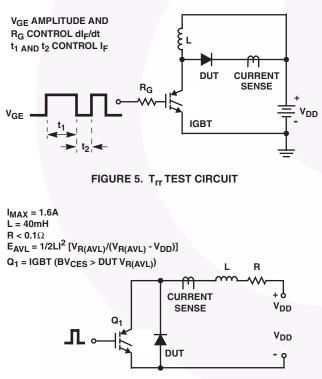
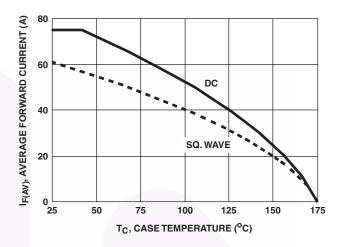
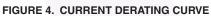
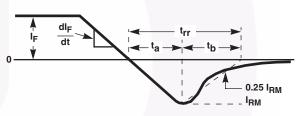
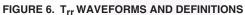


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT









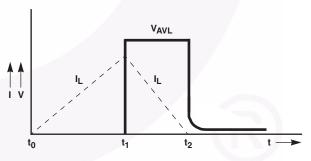
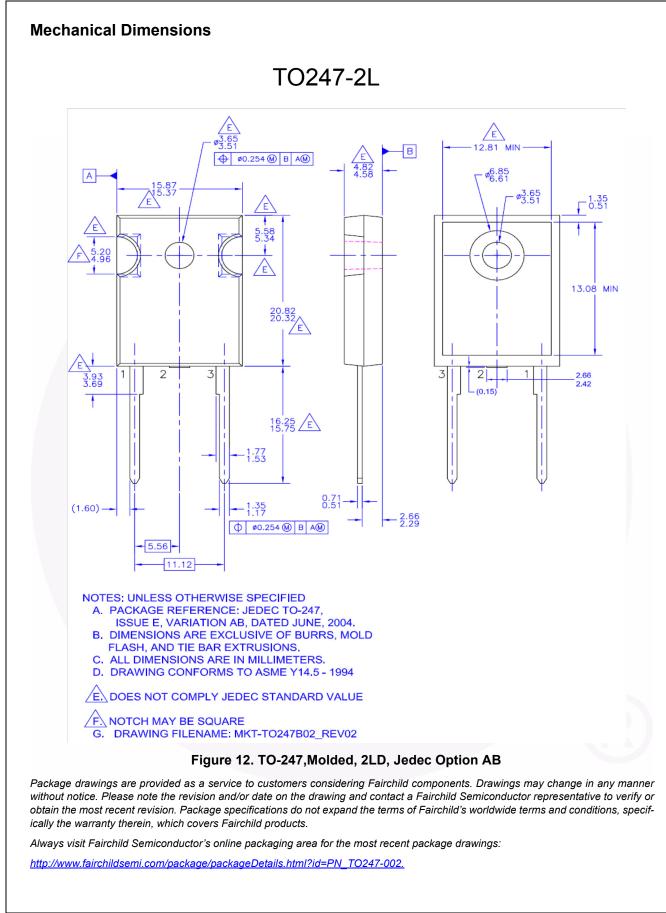


FIGURE 8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS





SEMICONDUCTOR

# RHRG30120 — Hyperfast Diode

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